



# **SB20-05P**

**Schottky Barrier Diode** 

# 50V, 2A Rectifier

### **Applications**

· High frequency rectification (switching regulators, converters, choppers).

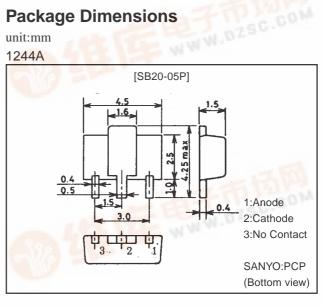
WW.DZSC.COM

### Features

- · Low forward voltage ( $V_F \max = 0.55V$ ).
- · Fast reverse recovery time (trr max=20ns).
- · Low switching noise.
- · Low leakage current and high reliability due to highly reliable planar structure.

## Package Dimensions

unit:mm



## **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

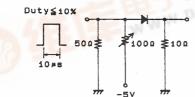
Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		50	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		55	V
Average Output Current	IO		2	А
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	10	А
Junction Temperature	Tj		-55 to +125	°C
Storage Temperature	Tstg		-55 to +125	°C

### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditons		Ratings		
			min	typ	max	Unit
Reverse Voltage	VR	I <sub>R</sub> =1mA	50			V
Forward Voltage	VF	I <sub>F</sub> =2A			0.55	V
Reverse Current	IR	V <sub>R</sub> =25V		1	200	μA
Interterminal Capacitance	С	V <sub>R</sub> =10V, f=1MHz	101-	120		pF
Reverse Recovery Time	trr	IF=IR=300mA, See sepcified Test Circuit	-6-	4.07	20	ns
Thermal Resistance	Rth(j-a) (1)		11.44	280		°C/W
	Rthj(j-a) (2)	Mounted on 250mm <sup>2</sup> ×0.8mm ceramic board		100		°C/W
		Mounted on 250mm <sup>2</sup> ×0.8mm ceramic board	100			

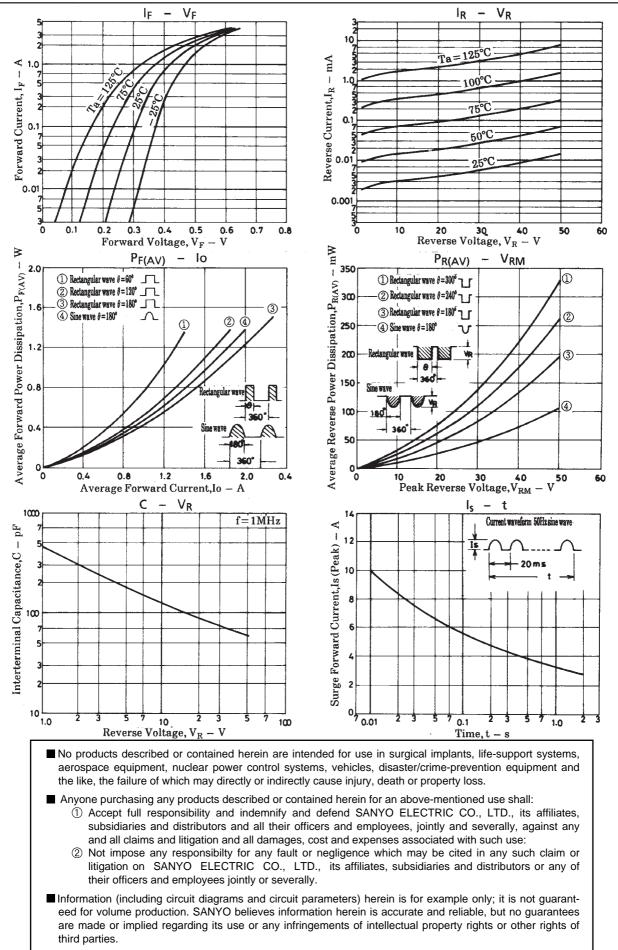
#### Marking:SH

#### trr Test Circuit



YO Electric Co., Ltd. Semiconductor Bussiness Headquaters OKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

SB20-05P



This catalog provides information as of March, 1998. Specifications and information herein are subject to change without notice.